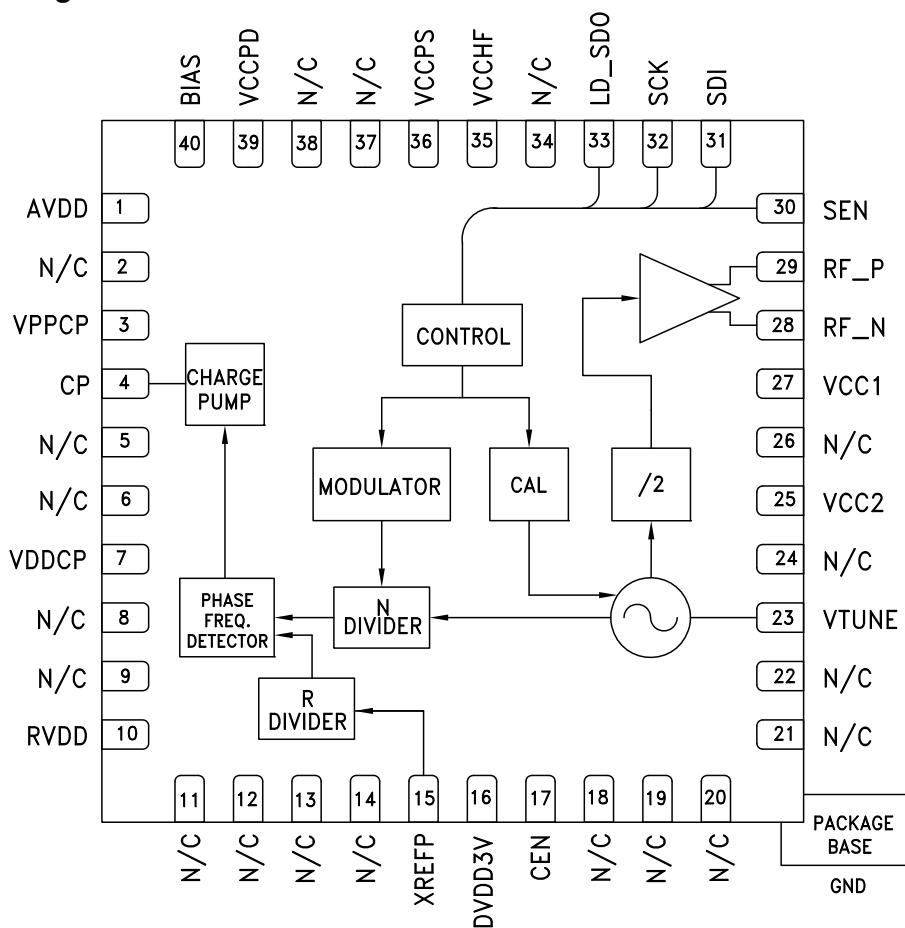



**FRACTIONAL-N PLL WITH
INTEGRATED VCO, 780 - 870 MHz**
Features

- RF Bandwidth: 780 to 870 MHz
- Ultra Low Phase Noise
-110 dBc/Hz in Band Typ.
- Figure of Merit (FOM) -227 dBc
- < 180 fs RMS Jitter
- 24-bit Step Size, Resolution 3 Hz typ
- Exact Frequency Mode
- Built-in Digital Self Test
- 40 Lead 6x6mm SMT Package: 36mm²

Typical Applications

- Cellular/4G Infrastructure
- Repeaters and Femtocells
- Communications Test Equipment
- CATV Equipment
- Phased Array Applications
- DDS Replacement
- Very High Data Rate Radios

Functional Diagram



**FRACTIONAL-N SYNTHESIZER WITH
INTEGRATED VCO, 780 - 870 MHz**

General Description

The HMC824LP6CE is a fully functioned Fractional-N Phase-Locked-Loop (PLL) with an Integrated Voltage Controlled Oscillator (VCO). The PLL consists of an integrated low noise VCO with divide-by-2 output, an autocalibration subsystem for low voltage VCO tuning, a very low noise digital Phase Detector (PD), a precision controlled charge pump, a low noise reference path divider and a fractional divider.

The fractional PLL features an advanced delta-sigma modulator design that allows both ultra-fine step sizes and low spurious products. The phase detector (PD) features cycle slip prevention (CSP) technology to allow faster frequency hopping times. Ultra low in-close phase noise and low spurious also allows wider loop bandwidths for faster frequency hopping and low micro-phonics.

For theory of operation and register map refer to the “[PLLs with Integrated VCOs - RF VCOs Operating Guide](#)”. To view the Operating Guide, please visit www.hittite.com and choose HMC824LP6CE from the “Search by Part Number” pull down menu.

Electrical Specifications, $T_A = +25^\circ C$

VPPCP, VDDCP, VCC1, VCC2 = 5V $\pm 4\%$; RVDD, AVDD, DVDD3V, VCCPD, VCCHF, VCCPS = 3.3V $\pm 6\%$ GNDCP = GNDLS = Ground Paddle = 0V

| Parameter | Condition | Min. | Typ. | Max. | Units |
|---|--|------|------|---------|-------|
| RF Output Characteristics | | | | | |
| VCO Frequency at PLL Input | | 1560 | | 1740 | MHz |
| RF Output Frequency at $f_{VCO}/2$ | | 780 | | 870 | MHz |
| RF Output Power at $f_{VCO}/2$ | | 11 | 14 | 16.5 | dBm |
| VCO Tuning Sensitivity | Measured at 2 GHz, 2V | | 15 | | MHz/V |
| VCO Supply Pushing | Measured at 2 GHz, 2V | -2 | | 1.5 | MHz/V |
| RF Output 2nd Harmonic | | | -25 | | dBc |
| RF Output 3rd Harmonic | | | -23 | | dBc |
| RF Output 4th Harmonic | | | -31 | | dBc |
| RF Divider Characteristics | | | | | |
| 19-Bit N-Divider Range (Integer) | Max = $2^{19} - 1$ | 16 | | 524,287 | |
| 19-Bit N-Divider Range (Fractional) | Fractional nominal divide ratio varies (-3 / +4) dynamically max | 20 | | 524,283 | |
| REF Input Characteristics | | | | | |
| Max Ref Input Frequency | Synthesizer phase noise can degrade by about 5dB when operating with a reference frequency near the low end of this range. | 10 | 50 | 200 | MHz |
| Ref Input Range | AC Coupled | 1.5 | 2 | 3.3 | Vpp |
| Ref Input Capacitance | | | | 5 | pF |
| 14-Bit R-Divider Range | | 1 | | 16,383 | |
| Phase Detector (PD) | | | | | |
| PD Frequency Fractional Feedback Mode | [1] | 0.1 | | 100 | MHz |
| PD Frequency Fractional Feedforward Mode (and Register 6 [17:16]= 10) | | 0.1 | | 80 | MHz |
| PD Frequency Integer Mode | [1] | 0.1 | | 125 | MHz |

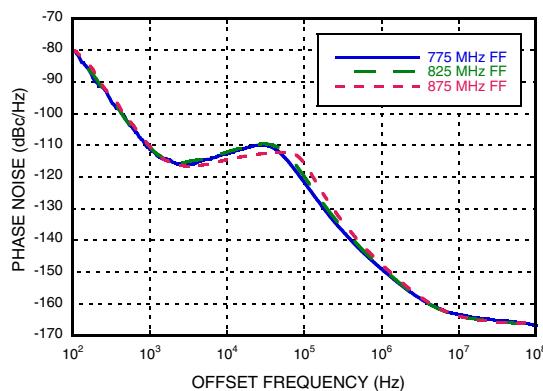
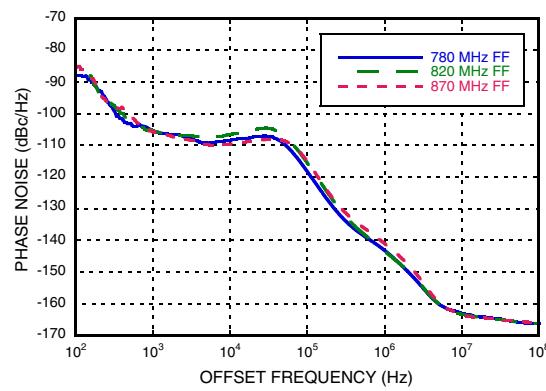
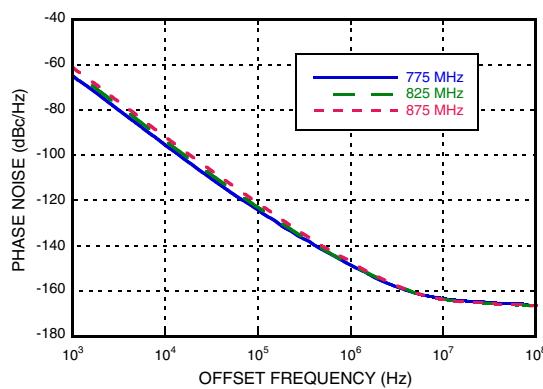
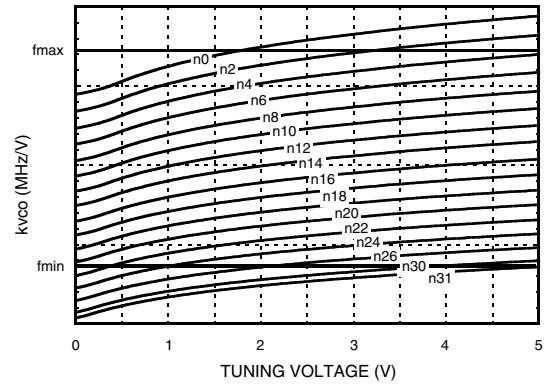
Note 1: This maximum phase detector frequency can only be achieved if the minimum N value is respected. eg. In the case of fractional feedback mode, the maximum PFD rate = $f_{VCO}/20$ or 100MHz, whichever is less.


**FRACTIONAL-N SYNTHESIZER WITH
INTEGRATED VCO, 780 - 870 MHz**
Electrical Specifications (Continued)

| Parameter | Condition | Min. | Typ. | Max. | Units |
|--|---------------------------------------|------------|------|--------|--------|
| Charge Pump | | | | | |
| Max Output Current | | 0.2 | | 2.54 | mA |
| Charge Pump Gain Step Size (5-Bits) | | | 20 | | µA |
| PD/Charge Pump SSB Phase Noise | 50 MHz Ref, Input Referred | | | | |
| 1 kHz | | | -141 | | dBc/Hz |
| 10 kHz | Add 1 dB for Fractional | | -149 | | dBc/Hz |
| 100 kHz | Add 3 dB for Fractional | | -153 | | dBc/Hz |
| Logic Inputs | | | | | |
| VIH Input High Voltage | | DVDD3V-0.4 | | DVDD3V | V |
| VIL Input Low Voltage | | 0 | | 0.4 | V |
| Logic Outputs | | | | | |
| VOH Output High Voltage | | DVDD3V-0.4 | | DVDD3V | V |
| VOL Output Low Voltage | | 0 | | 0.4 | V |
| Power Supply Voltages | | | | | |
| Analog 3.3V Supplies | AVDD, VCCHF, VCCPS, VCCPD, RVDD | 3.0 | 3.3 | 3.5 | V |
| Digital Supply | DVDD3V | 3.0 | 3.3 | 3.5 | V |
| Analog 5V Supplies | VPPCP, VDDCP, VCC1, VCC2 | 4.8 | 5 | 5.2 | V |
| Power Supply Currents | | | | | |
| +5V Analog Charge Pump | VPPCP, VDDCP | | 5.3 | | mA |
| +5V VCO Core and PLL Buffer | VCC2 | | 56 | | mA |
| +5V VCO Divider and RF Buffer | VCC1 | | 36 | | mA |
| +3.3V Analog | AVDD, VCCHF, VCCPS, VCCPD, RVDD | | 45 | | mA |
| +3.3V Digital | DVDD3V | | 6.5 | | mA |
| Power Down - Crystal Off | Reg 01h=0, Crystal Not Clocked | | 10 | | µA |
| Power Down - Crystal On, 100 MHz | Reg 01h=0, Crystal Clocked 100 MHz | | 10 | 200 | µA |
| Power on Reset | | | | | |
| Typical Reset Voltage on DVDD | | | 700 | | mV |
| Min DVDD Voltage for No Reset | | 1.5 | | | V |
| Power on Reset Delay | | | 250 | | µs |
| VCO Open Loop Phase Noise at fvco/2 | | | | | |
| 825 MHz Divide-by-2 Output | 10 kHz Offset | | -93 | | dBc/Hz |
| 825 MHz Divide-by-2 Output | 100 kHz Offset | | -123 | | dBc/Hz |
| 825 MHz Divide-by-2 Output | 1 MHz Offset | | -148 | | dBc/Hz |
| 825 MHz Divide-by-2 Output | 10 MHz Offset | | -162 | | dBc/Hz |
| 825 MHz Divide-by-2 Output | 100 MHz Offset | | -166 | | dBc/Hz |
| Closed Loop Phase Noise PLL + VCO at fvco/2 | | | | | |
| Integer, 25 MHz PFD | 1 kHz Offset | | -112 | | dBc/Hz |
| Integer, 25 MHz PFD | 10 kHz Offset | | -116 | | dBc/Hz |
| Integer, 25 MHz PFD | 100 kHz Offset | | -118 | | dBc/Hz |
| Integer, 25 MHz PFD | 1 MHz Offset | | -146 | | dBc/Hz |


**FRACTIONAL-N SYNTHESIZER WITH
INTEGRATED VCO, 780 - 870 MHz**
Electrical Specifications (Continued)

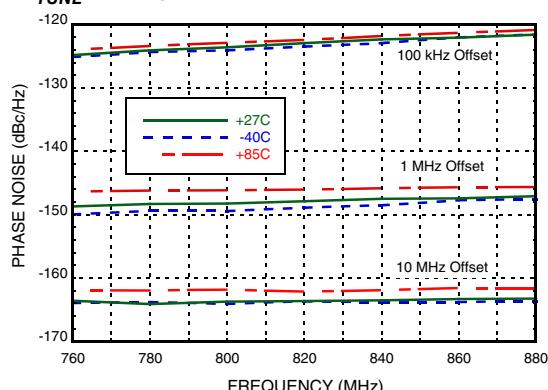
| Parameter | Condition | Min. | Typ. | Max. | Units |
|------------------------|---|------|------|------|--------|
| Fractional, 25 MHz PFD | 1 kHz Offset | | -107 | | dBc/Hz |
| Fractional, 25 MHz PFD | 10 kHz Offset | | -113 | | dBc/Hz |
| Fractional, 25 MHz PFD | 100 kHz Offset | | -115 | | dBc/Hz |
| Figure of Merit | Normalized 1 Hz | | | | |
| Integer Mode | Measured w/ 50 MHz PD at 30 kHz Offset | | -229 | | dBc/Hz |
| Fractional Mode | Measured w/ 50 MHz PD at 30 kHz Offset | | -227 | | dBc/Hz |

Closed Loop Integer Phase Noise

Typical Closed Loop Fractional Phase Noise [1]

VCO/2 Free Running Phase Noise

Typical VCO/2 Tuning Curves vs. Switch Position


[1] Fractional Mode, 50 MHz Crystal, R=1, ~80 kHz Loop BW, (Loop filter values: Contact factory for component values) 2mA Charge Pump, -385 μ A Offset.

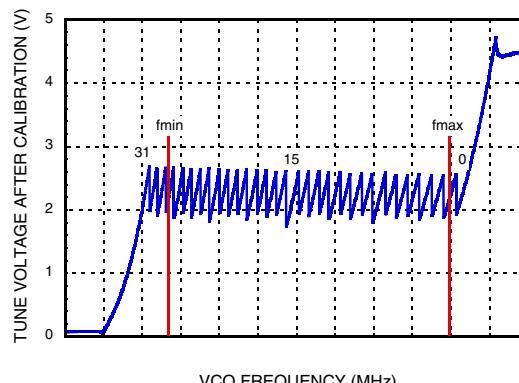


Free Running VCO Phase Noise (V_{TUNE} Set by AutoCal)

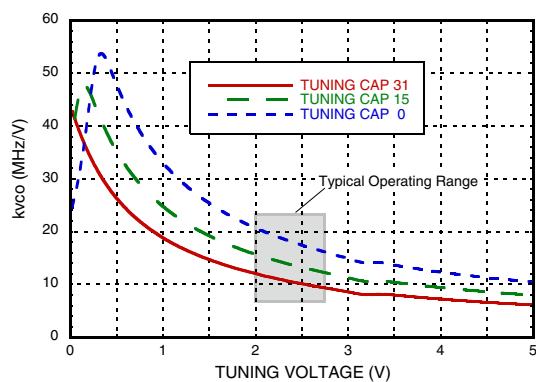


FRACTIONAL-N SYNTHESIZER WITH INTEGRATED VCO, 780 - 870 MHz

Typical VCO Tuning Voltage After Calibration



Typical VCO Sensitivity vs. Cap @ Fo Voltage



Typical Output Power - Narrow Band Match

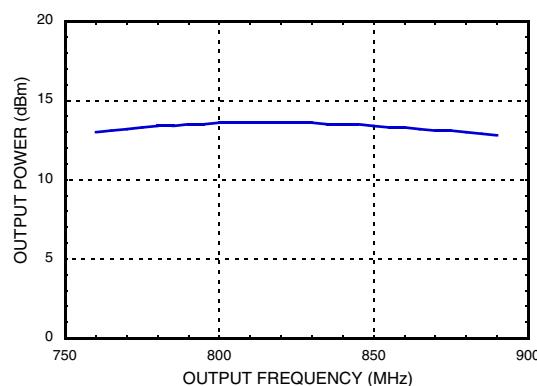
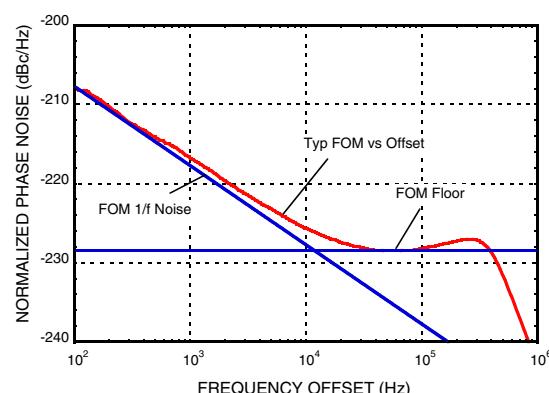


Figure of Merit




**FRACTIONAL-N SYNTHESIZER WITH
INTEGRATED VCO, 780 - 870 MHz**
Pin Descriptions

| Pin Number | Function | Description |
|---|----------|--|
| 1 | AVDD | DC Power Supply for analog circuitry. |
| 2, 5, 6, 8, 9, 11 - 14, 18 - 22, 24, 26, 34, 37, 38 | N/C | The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally. |
| 3 | VPPCP | Power Supply for charge pump analog section |
| 4 | CP | Charge Pump Output |
| 7 | VDDCP | Power Supply for the charge pump digital section |
| 10 | RVDD | Reference Supply |
| 15 | XREFP | Reference Oscillator Input |
| 16 | DVDD3V | DC Power Supply for Digital (CMOS) Circuitry |
| 17 | CEN | Chip Enable. Connect to logic high for normal operation. |
| 23 | VTUNE | VCO Varactor. Tuning Port Input. |
| 25 | VCC2 | VCO Analog Supply 2 |
| 27 | VCC1 | VCO Analog Supply 1 |
| 28 | RF_N | VCO Divide by 2 RF Positive Output |
| 29 | RF_P | VCO Divide by 2 RF Negative Output |
| 30 | SEN | PLL Serial Port Enable (CMOS) Logic Input |
| 31 | SDI | PLL Serial Port Data (CMOS) Logic Input |
| 32 | SCK | PLL Serial Port Clock (CMOS) Logic Input |
| 33 | LD_SDO | Lock Detect, or Serial Data, or General Purpose (CMOS) Logic Output (GPO) |
| 35 | VCCHF | DC Power Supply for Analog Circuitry |
| 36 | VCCPS | DC Power Supply for Analog Prescaler |
| 39 | VCCPD | DC Power Supply for Phase Detector |
| 40 | BIAS | External bypass decoupling for precision bias circuits. Note: $1.920V \pm 20mV$ reference voltage (BIAS) is generated internally and cannot drive an external load. Must be measured with $10G\Omega$ meter such as Agilent 34410A, normal $10M\Omega$ DVM will read erroneously. |



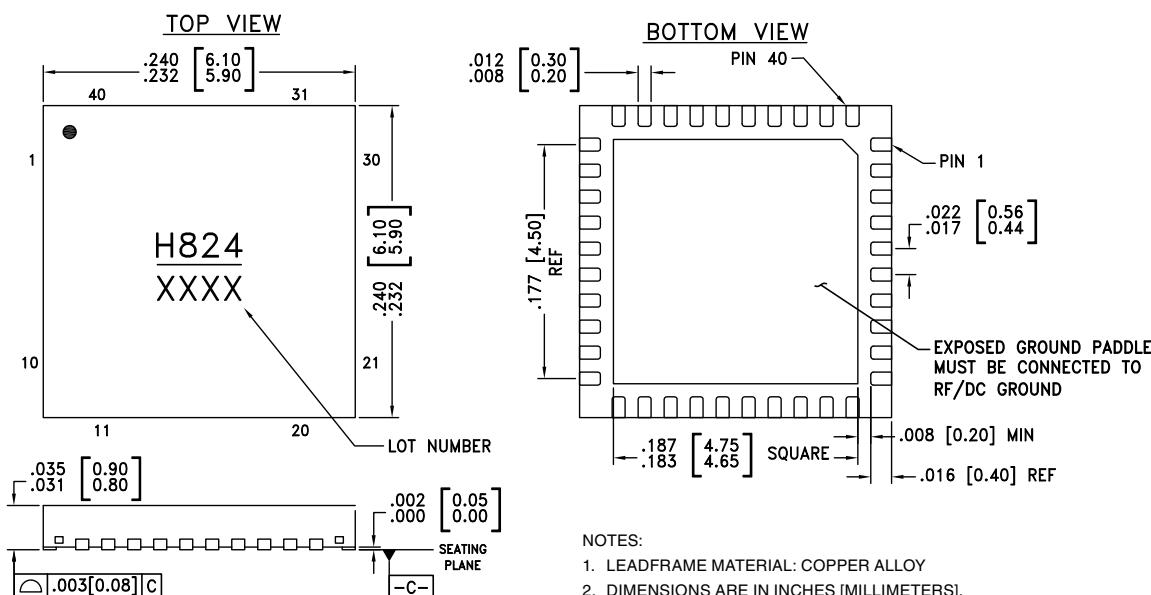
FRACTIONAL-N SYNTHESIZER WITH INTEGRATED VCO. 780 - 870 MHz

Absolute Maximum Ratings

| | |
|--|----------------|
| AVDD, RVDD, DVDD3V, VCCPD, VCCHF, VCCPS | -0.3V to +3.6V |
| VPPCP, VDDCP, VCC1 | -0.3V to +5.8V |
| VCC2 | -0.3V to +5.5V |
| Operating Temperature | -40°C to +85°C |
| Storage Temperature | -65°C to 125°C |
| Maximum Junction Temperature | 125 °C |
| Thermal Resistance (R_{TH}) (junction to ground paddle) | 20 °C/W |
| Reflow Soldering | |
| Peak Temperature | 260°C |
| Time at Peak Temperature | 40 sec |
| ESD Sensitivity (HBM) | Class 1B |

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Outline Drawing



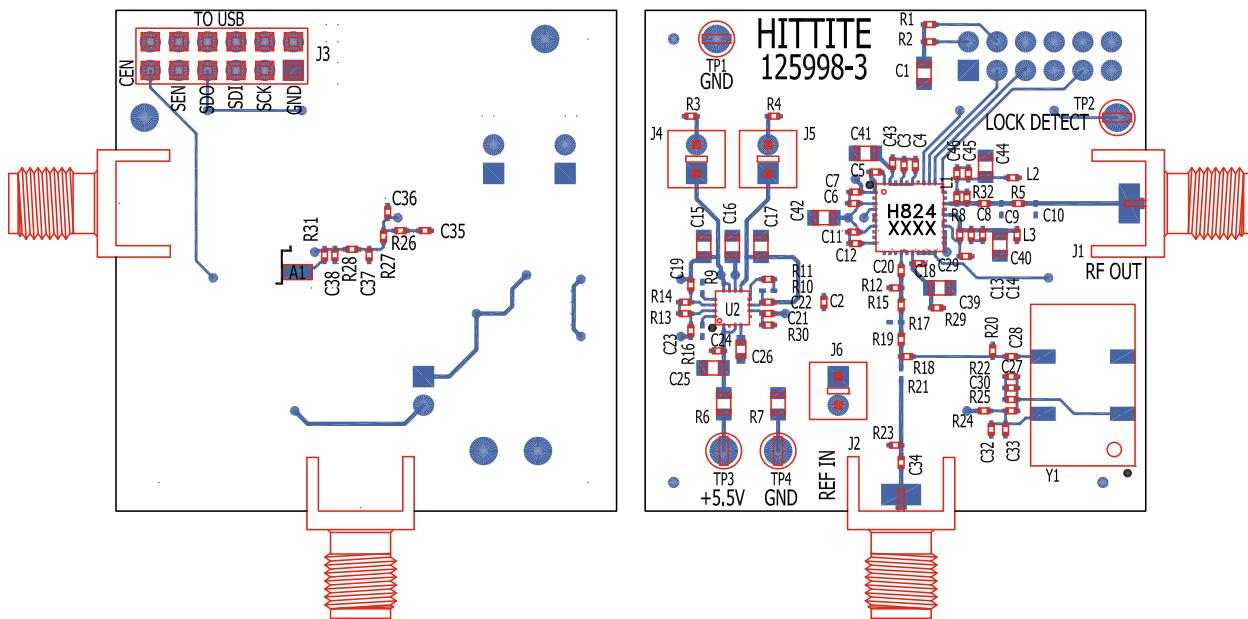
Package Information

| Part Number | Package Body Material | Lead Finish | MSL Rating | Package Marking ^[1] |
|-------------|--|---------------|------------|--------------------------------|
| HMC824LP6CE | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL1 | H824 XXXX |

[1] 4-Digit lot number XXXX

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**FRACTIONAL-N SYNTHESIZER WITH
INTEGRATED VCO, 780 - 870 MHz**
Evaluation PCB


The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

Evaluation PCB Schematic

To view this [Evaluation PCB Schematic](#) please visit www.hittite.com and choose HMC824LP6CE from the "Search by Part Number" pull down menu to view the product splash page.


**FRACTIONAL-N SYNTHESIZER WITH
INTEGRATED VCO, 780 - 870 MHz**
List of Materials for Evaluation PCB 127828 ^[1]

| Item | Description |
|---|---|
| J1, J2 | PCB Mount SMA RF Connector |
| J3 | Dual Row Terminal Strip |
| J4 - J6 | Connector Header |
| C1, C15 - C17, C25 | 10 μ F Capacitor, 0805 Pkg. |
| C2, C3, C6, C7, C11, C12, C14, C18, C27, C43, C45 | 0.47 μ F Capacitor, 0402 Pkg. |
| C4, C13 | 22 pF Capacitor, 0402 Pkg. |
| C5, C33 | 1000 pF Capacitor, 0402 Pkg. |
| C8 | 2.2 pF Capacitor, 0402 Pkg. |
| C19 - C24, C28, C30, C32, C34 | 0.1 μ F Capacitor, 0402 Pkg. |
| C26 | 1.0 μ F Capacitor, 0603 Pkg. |
| C29 | 47 pF Capacitor, 0402 Pkg. |
| C35 | 3300 pF Capacitor, 0402 Pkg. |
| C36 | 270 pF Capacitor, 0402 Pkg. |
| C37, C38 | 68 pF Capacitor, 0402 Pkg. |
| C39 - C42, C44 | 4.7 μ F Tantalum Capacitor, 0805 Pkg |
| C46 | 27 pF Capacitor, 0402 Pkg. |
| R1, R2, R5, R11, R15, R18, R19, R21, R24 | Zero Ohm Resistor, 0402 Pkg. |
| R3, R4 | 1 Ohm Resistor, 0402 Pkg. |
| R6, R7 | 0 Ohm Resistor, 0805 Pkg. |
| R8 | 22 Ohm Resistor, 0402 Pkg. |
| R12, R20, R29 | 51 Ohm Resistor, 0402 Pkg. |
| R22, R25 | 20 kOhm Resistor, 0402 Pkg. |
| R26 - R28 | 1k Ohm Resistor, 0402 Pkg. |
| L1 | 12 nH Inductor, 0402 Pkg. |
| L2, L3 | 47 nH Inductor, 0402 Pkg/ |
| TP3, TP4 | Test Point PC Compact SMT |
| U1 | HMC824LP6CE PLL with Integrated VCO |
| U2 | HMC860LP3E Low Noise Quad Linear Regulator |
| Y1 | 3.3V, 50 MHz VCXO Crystal Oscillator |
| PCB ^[2] | 125998 Evaluation Board |

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350 or Arlon 25FR and FR4

**FRACTIONAL-N SYNTHESIZER WITH
INTEGRATED VCO, 780 - 870 MHz****Notes:**